

Features

- ESD Protected up to 2KV (HBM)
- · High Speed Switching
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

P-Channel MOSFET

Maximum Ratings

Operating Junction Temperature Range : -55°C to +150°C

Storage Temperature Range: -55°C to +150°C

• Maximum Thermal Resistance: 130°C/W Junction to Ambient^(Note 2)

Parameter		Symbol	Rating	Unit	
Drain -source Voltage		V _{DS}	-60	V	
Gate -Source Voltage		V_{GS}	±20	V	
Drain Current-Continuous	T _A =25°C	l _D	-0.13	Α	
	T _A =100°C		-0.08		
Pulsed Drain Current ^(Note 3)		I _{DM}	-0.52	Α	
Power Dissipation ^(Note 4)		P _D	0.96	W	

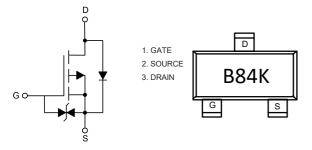
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_{D} is based on max. junction temperature, using junction-ambient thermal resistance.

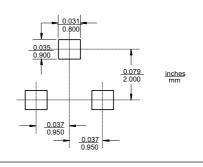
SOT-23

DIMENSIONS						
DIM INCHE		HES	ES MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.110	0.120	2.80	3.04		
В	0.083	0.104	2.10	2.64		
С	0.047	0.055	1.20	1.40		
D	0.034	0.041	0.85	1.05		
E	0.067	0.083	1.70	2.10		
F	0.018	0.024	0.45	0.60		
G	0.0004	0.006	0.01	0.15		
Н	0.035	0.043	0.90	1.10		
J	0.003	0.007	0.08	0.18		
K	0.012	0.020	0.30	0.51		
L	0.007	0.020	0.20	0.50		

Internal Structure and Marking Code Suggester



Suggested Solder Pad Layout





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Static Characteristics						II.
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-60			V
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.8	-1.5	-2.5	V
Gate-Body Leakage Current	I _{GSS}	V _{GS} =± 20V, V _{DS} =0V			±10	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V			-1	μΑ
Drain-Source On-Resistance	Б	V _{GS} =-10V, I _D =-0.5A		2.2	6	
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-0.2A		2.5	7	Ω
Forward Transconductance	g FS	V _{DS} =-5V, I _D =-0.13A		0.37		S
Gate Resistance	R _g	f=1 MHz, Open drain		1038		Ω
Diode Characteristics			•			
Continuous Body Diode Current	I _S				-0.13	А
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-0.5A			-1.3	V
Reverse Recovery Time	t _{rr}	1 - 0 20 41 /44-4000/		13		ns
Reverse Recovery Charge	Q _{rr}	l _F =-0.3A, dl _F /dt=100A/μs		7		nC
Dynamic Characteristics	•					
Input Capacitance	C _{iss}			37		
Output Capacitance	C _{oss}	V _{DS} =-30V,V _{GS} =0V,f=1MHz		5.8		pF
Reverse Transfer Capacitance	C _{rss}			3.7		
Total Gate Charge	Qg			2.55		
Gate-Source Charge	Q _{gs}	V _{DS} =-30V,V _{GS} =-10V,I _D =-0.3A		0.45		nC
Gate-Drain Charge	Q _{gd}			0.44		
Turn-On Delay Time	t _{d(on)}			4.6		
Turn-On Rise Time	t _r	V _{DD} =-30V,V _{GS} =-10V,		3.7		20
Turn-Off Delay Time	t _{d(off)}	$R_{G}=2.5\Omega$, $I_{D}=-0.3A$		35		- ns
Turn-Off Fall Time	t _f			19		



Curve Characteristics

Fig.1 - Typical Output Characteristics

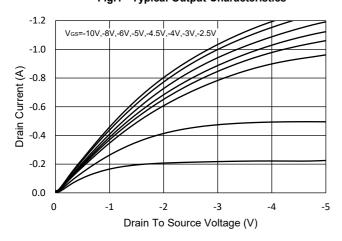


Fig.2 - Transfer Characteristic

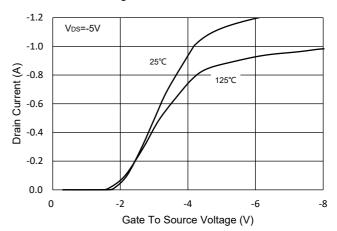


Fig.3 - $R_{\rm DS(ON)}$ - $V_{\rm GS}$

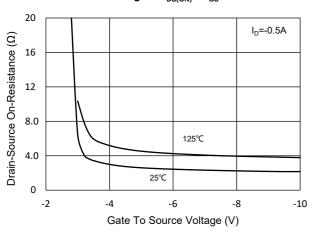


Fig.4 - $R_{DS(ON)}$ - I_D

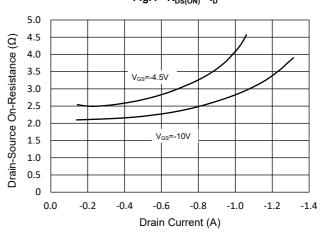


Fig.5 - Capacitance Characteristics

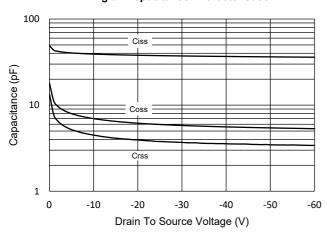
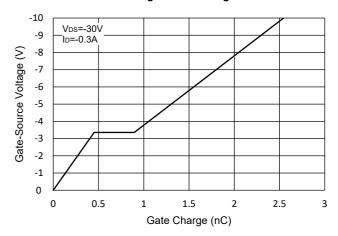


Fig.6 - Gate Charge



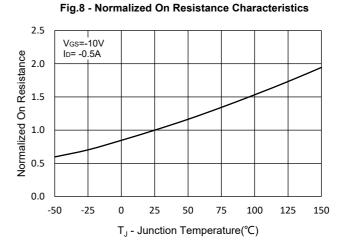


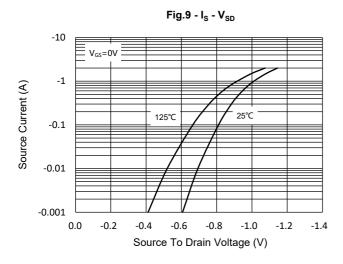
Curve Characteristics

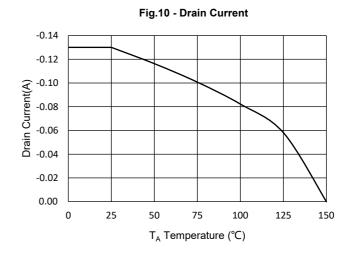
Fig.7 - Normalized Threshold Voltage

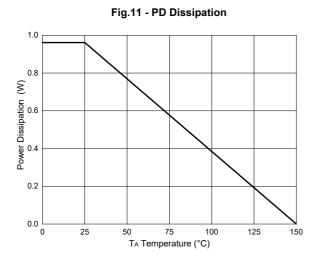
1.2

| Solution | Possible |



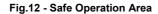








Curve Characteristics



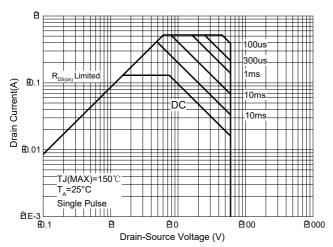
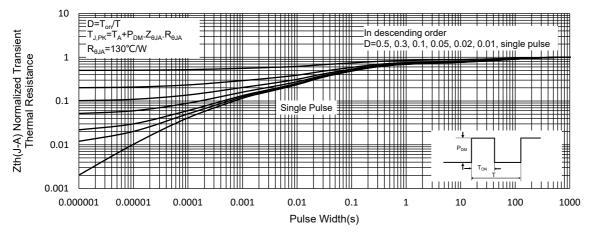


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel:3Kpcs/Reel	

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